

### **Abstract of the Disclosure**

There is provided a structure comprising semiconductor material, the structure having at least one zone of reduced oxygen concentration, such zone having an interstitial oxygen concentration of not greater than  $3 \times 10^{17}$  oxygen atoms/cm<sup>3</sup>, such zone extending at least 75 microns in depth from a first major surface. There is further provided a photovoltaic cell comprising at least one such structure.